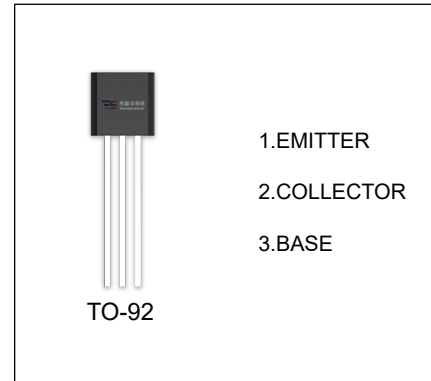


## BC237 / BC238 / BC239 TRANSISTOR (NPN)

### FEATURES

Amplifier dissipation NPN Silicon



### ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
BC237	TO-92	Bulk	1000pcs/Bag
BC237-TA	TO-92	Tape	2000pcs/Box
BC238	TO-92	Bulk	1000pcs/Bag
BC238-TA	TO-92	Tape	2000pcs/Box
BC239	TO-92	Bulk	1000pcs/Bag
BC239-TA	TO-92	Tape	2000pcs/Box

### MAXIMUM RATINGS (T<sub>a</sub>=25 °C unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>CEO</sub>	Collector-Emitter Voltage	BC237	45
		BC238/239	25
V <sub>EBO</sub>	Emitter-Base Voltage	BC237	6
		BC238/239	5
I <sub>C</sub>	Collector Current -Continuous	0.1	A
P <sub>C</sub>	Collector Power Dissipation	350	mW
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient	357	°C /W
R <sub>θJC</sub>	Thermal Resistance, Junction to Case	125	°C /W
T <sub>J</sub> , T <sub>stg</sub>	Operation Junction and Storage Temperature Range	-55~150	°C

**$T_a=25^\circ\text{C}$  unless otherwise specified**

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=100\mu\text{A}, I_E=0$ BC237	50			V
		BC238/239	30			
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=2\text{mA}, I_B=0$ BC237	45			V
		BC238/239	25			
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=100\mu\text{A}, I_C=0$ BC237	6			V
		BC238/239	5			
Collector cut-off current	$I_{CBO}$	$V_{CE}=50\text{V}, V_{BE}=0$ BC237 $V_{CB}=30\text{V}, I_E=0$ BC238/239			15	nA
DC current gain	$h_{FE(1)}$	$V_{CE}=5\text{V}, I_C=10\mu\text{A}$ BC237A		90		
		BC237B/238B		150		
		BC237C/238C/239C		270		
	$h_{FE(2)}$	$V_{CE}=5\text{V}, I_C=2\text{mA}$ BC237	120		800	
		BC239	120		800	
		BC237A	120		220	
		BC237B/238B	200		460	
		BC237C/238C/239C	380		800	
	$h_{FE(3)}$	$V_{CE}=5\text{V}, I_C=100\text{mA}$ BC237A		120		
		BC237B/238B		180		
		BC237C/238C/239C		300		
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=10\text{mA}, I_B=0.5\text{mA}$ BC237/238/239			0.2	V
		$I_C=100\text{mA}, I_B=5\text{mA}$ BC237/239			0.6	
		BC238			0.8	
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=10\text{mA}, I_B=0.5\text{mA}$ $I_C=100\text{mA}, I_B=5\text{mA}$			0.83 1.05	V
Base-emitter voltage	$V_{BE}$	$V_{CE}=5\text{V}, I_C=0.1\text{mA}$		0.5		V
		$V_{CE}=5\text{V}, I_C=2\text{mA}$	0.55		0.7	
		$V_{CE}=5\text{V}, I_C=100\text{mA}$		0.83		
Transition frequency	$f_T$	$V_{CE}=3\text{V}, I_C=0.5\text{mA}, f=100\text{MHz}$ BC237		100		MHz
		BC238		120		
		BC239		140		
		$V_{CE}=5\text{V}, I_C=10\text{mA}, f=100\text{MHz}$ BC237	150	200		
		BC238	150	240		
		BC239	150	280		
Collector output capacitance	$C_{ob}$	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$			4.5	pF
Emitter-base capacitance	$C_{ib}$	$V_{EB}=0.5\text{V}, I_C=0, f=1\text{MHz}$		8		Pf
Noise figure	NF	$V_{CE}=5\text{V}, I_C=0.2\text{mA},$ $f=1\text{kHz}, R_s=2\text{K}\Omega$ BC239		2	4	dB
		$V_{CE}=5\text{V}, I_C=0.2\text{mA},$ $f=1\text{kHz}, R_s=2\text{K}\Omega, \Delta f=200\text{Hz}$ BC237		2	10	
		BC238		2	10	
		BC239		2	4	